

CRM PFC control IC and LLC current resonant control IC for high power factor and low THD power supplies

# FA1B10N/FA6C64N

## High power factor and low THD with worldwide input voltage



High power factor and low THD



Low standby power



**Reduce components** 

The FA1B10N critical conduction mode PFC control IC and FA6C64N LLC current resonant control IC are suitable for LED driver power supplies. They achieve high power factor and low THD (Total Harmonic Distortion)\*1, and have a built-in auto burst function that ensures high efficiency even at light loads. They are applicable to a variety of CVCC control power supplies.

\*1: THD is a value that expresses the degree of voltage and current distortion; where the lower the value, the lower the distortion.

• Improve power factor and THD : Achieve a power factor of 95% or higher and THD of 5% or lower at a 230 Vac input voltage

and at 50% of the typical output power

: Achieve input power of 300 mW or less at an input voltage of 230 Vac and no load · Achieve low standby power

· Auto burst function : Can automatically switch to burst

 Reduce components in power supply: No need for auxiliary power and standby signal

· High reliability and high quality : ESD resistance  $\pm 2$  kV (HBM),  $T_a = -60$ °C, the capacitive mode prevention

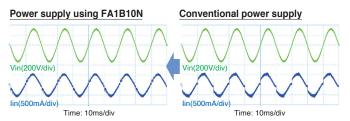
operation at light loads FA1B10N Package: SOP-8 FA6C64N Package: SOP-16

Application examples: LED driver power supplies, chargers, industrial power supplies

#### 1. Improve power factor and THD

It enables high power factor and low THD even at high input voltages due to the PFC control IC's power factor and THD improvement function.

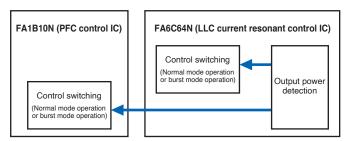
> 4.9% better than before Power factor: 93.3% to 98.2% 4.6% better than before : 9.3% to 4.7%



Vin=230Vac/50Hz, 50% Load (75W)

### 3. Auto burst function

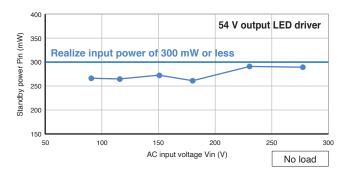
It detects output power using the FA6C64N, and can switch from normal mode operation to burst mode operation for both the FA1B10N and FA6C64N at light loads.



<sup>\*</sup>The switchable output power is adjustable

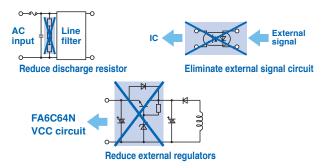
#### 2. Low standby power

It is possible to achieve an input power of 300 mW or less at no load under worldwide input voltage without an auxiliary power supply.



#### Reduce components in power supply

Reduce the number of components in power supply by built-in an X-CAP discharge function, auto burst mode control function, and FET drive power supply.



#### Table of FA1B10N PFC control IC functions

| Item                                      | FA1B10N                |
|---|------------------------|
| Power factor and THD improvement function | Built-in               |
| Auto burst mode function                  | Built-in               |
| X-CAP discharge function                  | Built-in               |
| Startup circuit                           | Built-in, 650 V        |
| Overcurrent protection                    | Built-in               |
| PFC overvoltage protection                | Built-in               |
| ESD guaranteed operating voltage (HBM)    | All pins ± 2 kV        |
| Operating ambient temperature             | -60°C to +150°C        |
| Package                                   | SOP8 (3.9 mm × 5.0 mm) |

#### Table of FA6C64N LLC control IC functions

| ltem                                   | FA6C64N                  |
|--|--------------------------|
| Auto burst mode function               | Built-in                 |
| X-CAP discharge function               | Built-in                 |
| Startup circuit                        | Built-in, 650 V          |
| High side driver                       | Built-in, 780 V          |
| Gate driver power supply               | Built-in                 |
| VCC pin voltage                        | 40 V withstand voltage   |
| Automatically adjusted dead time       | Built-in                 |
| Capacitive mode prevention function    | Built-in                 |
| Brownout protection                    | Built-in                 |
| Overcurrent protection                 | Built-in                 |
| Overload protection                    | Built-in                 |
| ESD guaranteed operating voltage (HBM) | All pins ± 2 kV          |
| Operating ambient temperature          | -60°C to +150°C          |
| Package                                | SOP16 (3.9 mm × 10.0 mm) |

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#### Safety Precautions

\*Before using this product, read the "Instruction Manual" and "Specifications" carefully, and consult with the retailer from which you purchased this product as necessary to use this product correctly.

\*The product must be handled by a technician with the appropriate skills.

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